

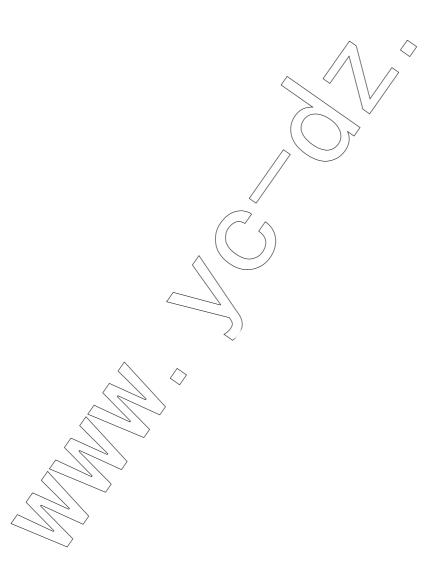
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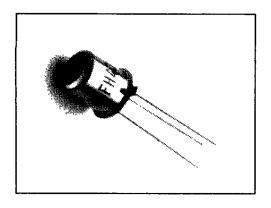


## SIEMENS

# SFH 431 SERIES

## **INFRARED EMITTER**



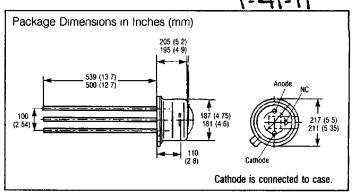


### **FEATURES**

- TO-18 Hermetic Package, 3-Leaded
- Dome Glass Lens
- Very Narrow Beam, ±8°
- Three High Power Intensity Ranges SFH 431 10 mW/Sr SFH 431-1 10-20 mW/Sr SFH 431-2 16-32 mW/Sr SFH 431-3 ≥25 mW/Sr
- Reversed Polarity Compared to SFH 401
- GaAs Material

#### **DESCRIPTION**

The SFH 431 is a GaAs infrared emitting diode which emits radiation in the near infrared range. The emitted radiation, which can be modulated, is caused by current in the forward direction. The SFH 431 comes in a 3-leaded TO-18 package and has a glass lens to provide a narrow emitting beam. The cathode lead is the lead closest to the tab. The cathode is electrically connected to the case. The SFH 431 is electrically similar to the SFH 401 series, but has a reversed pin out and case polarity



### **Absolute Maximum Ratings**

Parameter	Symbol	Min	Max	Unit
Power Dissipation	•		470	mW
DC Forward Current	l <sub>E</sub>		300	mA
Surge Current (t < 10 $\mu$ s, D = 0)	·		30	Α
Reverse Voltage	V <sub>R</sub>		50	٧
Storage Temperature	Ts	-55	100	°C
Operating Temperature	T <sub>A</sub>	-55	100	°C
Junction Temperature	Tj		100	°C
Lead Soldering Temperature	•			260°C for 5 sec
(1/8 inch from case)				

#### Electrical Characteristics (Tamb = 25°C)

- ( amb to c)						Test	
Parameter	Symbol	Min	Тур	Max	<b>Unit</b>	Conditions	
Forward Voltage	V <sub>F</sub>		13	15	٧	$l_F = 100 \text{ mA}$	
Forward Voltage	V <sub>F</sub>		19	25	V	l <sub>F</sub> = 1 A	
Reverse Current	l <sub>B</sub>		0.01	10	μА	$V_R = 5 \text{ V}$	
Peak Wavelength	λp	930	950	970	nm	$I_{\rm F} = 100  {\rm mA}$	
Half Angle	φ		+8		Dea	•	

The diodes are grouped according to their radiant intensity Ie in axial direction (at  $I_F = 100$  mA,  $t_P = 20$  ms).

Dash Number	SFH431	-1	-2	-3	Unit
Radiant Intensity I <sub>e</sub>	10	10-20	16-32	≥25	mW/Sr
Φ <sub>e</sub> (Total) typ	6	5	6	7	mW

### Radiant Characteristics $I_{rel} = f(\varphi)$

